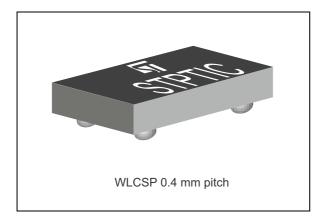


STPTIC-82G2

Parascan[™] tunable integrated capacitor

Datasheet - production data



Features

- High power capability
- 5:1 tuning range
- High linearity
- High quality factor (Q)
- Low leakage current
- Compatible with high voltage control IC (STHVDAC series)
- Available in wafer level chip scale package:
 WLCSP package 0.61 x 0.90 x 0.3 mm
- ECOPACK[®]2 compliant component

Benefit

• RF tunable passive implementation in mobile phones to optimize antenna radiated performance

Applications

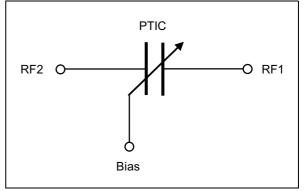
- Cellular antenna open loop tunable matching network in multi-band GSM/WCDMA/LTE mobile phone
- Open loop tunable RF filters

Description

The ST integrated tunable capacitor offers excellent RF performance, low power consumption and high linearity required in adaptive RF tuning applications. The fundamental building block of PTIC is a tunable material called Parascan[™], which is a version of barium strontium titanate (BST) developed by Paratek microwave.

BST capacitors are tunable capacitors intended for use in mobile phone application and dedicated to RF tunable applications. These tunable capacitors are controlled through an extended bias voltage ranging from 1 to 24 V. The implementation of BST tunable capacitor in mobile phones enables significant improvement in terms of radiated performance making the performance almost insensitive to the external environment.

Figure 1. PTIC functional block diagram



TM: Parascan is a trademark of Paratek Microwave Inc.

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This is information on a product in full production.

1 Electrical characteristics

| | | , | |
|-----------------------|--|-------------------------|------|
| Symbol | Parameter | Rating | Unit |
| P _{IN} | Input peak power RF _{IN} (CW mode)/all RF ports | +40 | dBm |
| V _{ESD(HBM)} | Human body model, JESD22-A114-B, all I/O | Class 1B ⁽¹⁾ | V |
| V _{ESD(MM)} | Machine model, JESD22-A115-A, all I/O | 100 | V |
| T _{device} | Device temperature | +125 | °C |
| T _{stg} | Storage temperature | -55 to +150 | C |
| V _x | Bias voltage | 25 | V |

Table 1. Absolute maximum ratings (limiting values)

1. Class 1B defined as passing 500 V, but fails after exposure to 1000V ESD pulse.

Table 2. Recommended operating conditions

| Symbol | Parameter | | Unit | | |
|---------------------|-----------------------|------|------|------|------|
| | Falanielei | Min. | Тур. | Max. | Unit |
| P _{IN} | RF input power | | +33 | | dBm |
| F _{OP} | Operating frequency | 700 | | 2700 | MHz |
| T _{device} | Device temperature | | | +100 | °C |
| T _{OP} | Operating temperature | -30 | | +85 | C |
| V _{BIAS} | Bias voltage | 1 | | 24 | V |



| Symbol | Parameter | | | L Incit | | | |
|------------------|-----------------------------|---|------|---------|-------|-------|--|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | |
| C _{1V} | capacitor at 1 V bias | STPTIC-82G2 | 8.54 | 9.7 | 10.86 | pF | |
| C _{2V} | capacitor at 2 V bias | STPTIC-82G2 | | 8.2 | | pF | |
| C _{24V} | capacitor at 24 V bias | STPTIC-82G2 | 1.53 | 1.66 | 1.79 | pF | |
| ΔC | Tuning range | Ratio between C _{1V} /C _{24V} ⁽¹⁾ | 5/1 | | | | |
| ١ _L | Leakage current | Measured with V _{bias} = 24 V | | | 100 | nA | |
| Q _{LB} | Quality factor | Measured at 700 MHz at 2 V | 55 | 65 | | | |
| Q _{HB} | Quality factor | Measured at 2700 MHz at 2 V | 35 | 50 | | | |
| IP3 | Third order intercept point | $V_{\text{bias}} = 1 V^{(2)(4)}$ | 52 | 60 | | dBm | |
| 15 | | $V_{\text{bias}} = 24 V^{(2)(4)}$ | | 75 | | UDIII | |
| H2 | Second harmonic | $V_{\text{bias}} = 1 V^{(3)(4)}$ | | -65 | -45 | dBm | |
| 112 | | $V_{\text{bias}} = 24 V^{(3)(4)}$ | | -75 | | UDIII | |
| H3 | Third harmonic | $V_{bias} = 1 V^{(3)(4)}$ | | -35 | -30 | dBm | |
| пэ | | $V_{\text{bias}} = 24 V^{(3)(4)}$ | | -65 | | UDIII | |
| + | Transition time | Average for any transition between $\rm C_{min}$ to $\rm C_{max}^{(5)}$ | | 40 | | | |
| t _T | Transition time | Average transition between C_{max} to $C_{min}^{(5)}$ | | 20 | | μs | |

Table 3. Representative performance (T_{amb} = 25 °C otherwise specified)

1. Measured at low frequency

2. F_1 = 894 MHz, F_2 = 849 MHz, P_1 = +25 dBm, P_2 = +25 dBm, $2f_1$ - f_2 = 939 MHz

3. 850 MHz, P_{in} = +34 dBm

4. IP3 and harmonics are measured in the shunt configuration in a 50 Ω environment

5. One or both of $\mathrm{RF}_{\mathrm{in}}$ and $\mathrm{RF}_{\mathrm{out}}$ must be connected to DC ground, using the HVDAC turbo mode



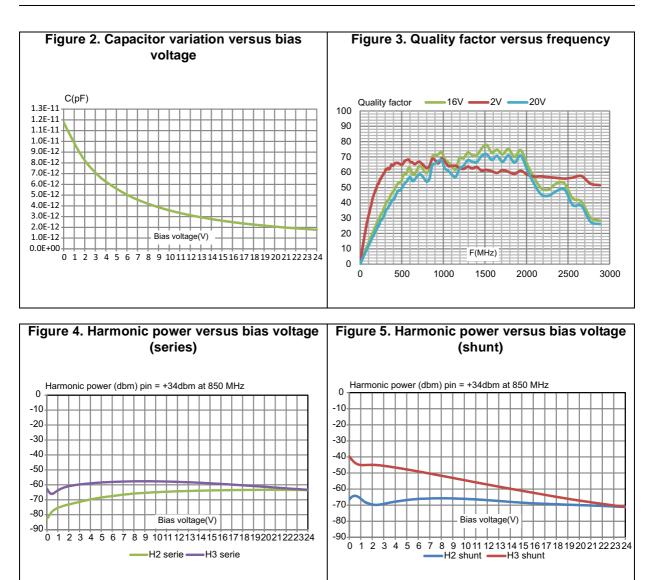
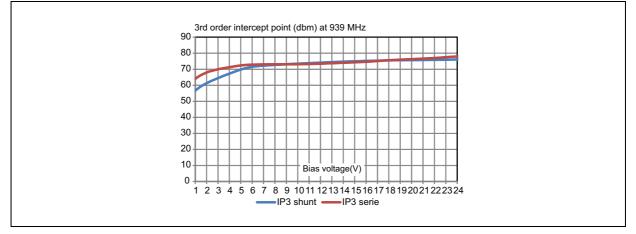


Figure 6. Third order intercept point (IP3)



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2 Package information

- Epoxy meets UL94, V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK[®] is an ST trademark.

2.1 Flip-Chip package information

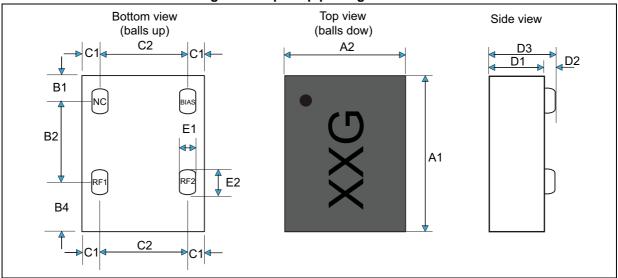


Figure 7. Flip-Chip package outline

The land pattern below is recommended for soldering the STPTIC-G2 on PCB.

NC stands for No Connect, this pad must not be connected on application board. Please leave this pad floating.

| Dimensions (micron) | A1 | A2 | B1 | B2 | В4 | C1 | C2 | D1 | D2 | D3 | E1 | E2 | | | |
|-------------------------|-----|-----|-----|-----|-----|--------|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| STPTIC-15/27/33/39/47G2 | 640 | | | | 120 | | | | | | | | | | |
| STPTIC-56G2 | 710 | 590 | 120 | 400 | 190 | 85 | 420 | 200 | 90 | 290 | 125 | 165 | | | |
| STPTIC-68G2 | 780 | | 120 | 120 | 120 | 50 120 | 100 | 260 | 00 | 420 | 200 | 30 | 230 | 125 | 105 |
| STPTIC-82G2 | 880 | | | | 360 | | | | | | | | | | |
| Tolerance | ±30 | ±30 | ±15 | ±10 | ±15 | ±15 | ±10 | ±20 | ±20 | ±40 | ±20 | ±20 | | | |

Table 4. Flip-Chip package dimensions



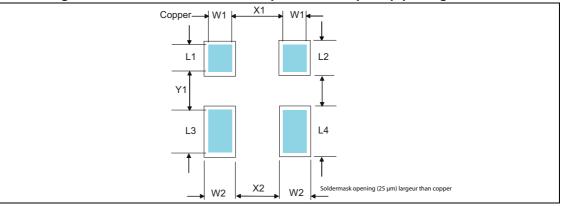




Table 5. Dimensions

| Dimensions | L1 | W1 | L3 | L2 | W2 | L4 | X1 | X2 | Y1 | Y2 |
|-------------------------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Typical values (micron) | 160 | 160 | 260 | 210 | 210 | 310 | 320 | 270 | 240 | 190 |

2.2 Packing information

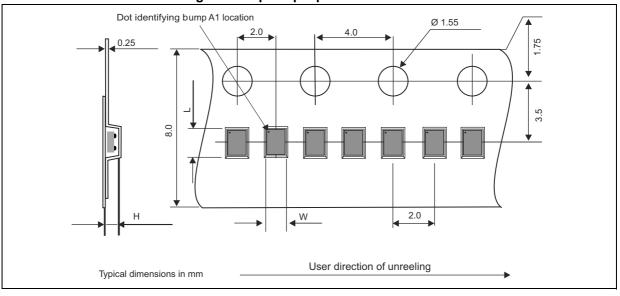


Figure 9. Flip-Chip tape and reel outline

Table 6. Dimensions

| Pocket dimensions | L | W | н |
|-------------------------|-----|-----|-----|
| STPTIC-15/27/33/39/47G2 | 730 | 680 | 380 |
| STPTIC-56G2 | 800 | 680 | 380 |
| STPTIC-68G2 | 870 | 680 | 380 |
| STPTIC-82G2 | 970 | 680 | 380 |



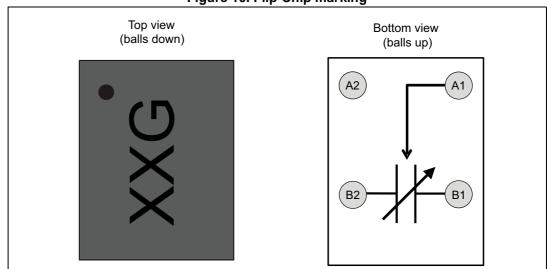


Figure 10. Flip-Chip marking

Table 7. Pinout description

| Pad / ball number | Pin name | Description |
|-------------------|----------|----------------------------------|
| A1 | DC bias | DC bias voltage |
| B1 | RF2 | RF input / output ⁽¹⁾ |
| A2 | NC | Not connected |
| B2 | RF1 | RF input / output |

1. When connected in shunt, please connect RF2 (B1 ball) to GND



3 Reflow profile

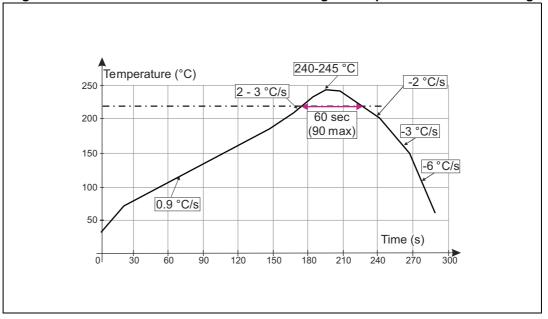


Figure 11. ST ECOPACK[®] recommended soldering reflow profile for PCB mounting



Minimize air convection currents in the reflow oven to avoid component movement.

| Drafila | Va | lue |
|---|---------------|---------|
| Profile | Typical | Max. |
| Temperature gradient in preheat (T = 70-180 °C) | 0.9 °C/s | 3 °C/s |
| Temperature gradient (T = 200-225 °C) | 2 °C/s | 3 °C/s |
| Peak temperature in reflow | 240-245 °C | 260 °C |
| Time above 220 °C | 60 s | 90 s |
| Temperature gradient in cooling | -2 to -3 °C/s | -6 °C/s |
| Time from 50 to 220 °C 160 to 220 s | | |

Table 8. Recommended values for soldering reflow



4 Evaluation board

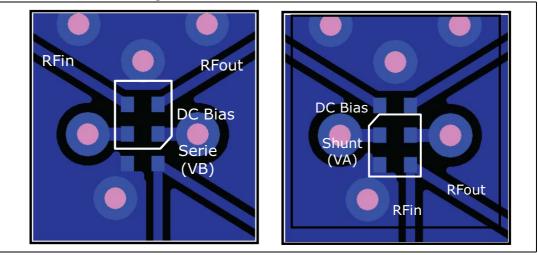


Figure 12. Series and shunt connection

Figure 13. Layer 1 and layer 4

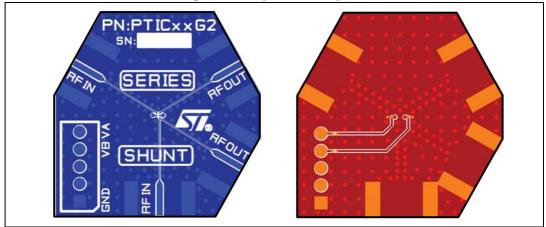
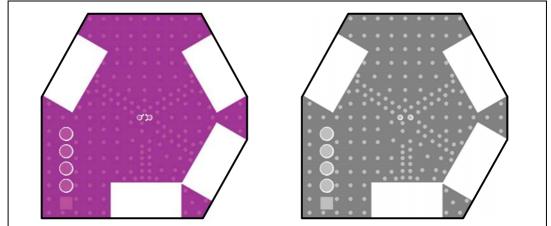


Figure 14. Layer 2 and layer 3





5 Ordering information

| | i igure i | <u></u> | | ormation schen | | |
|------------------------|---|---------|--|---|----------------------------------|------------------------|
| ST | PTIC | - | 15 | G | 2 | C5 |
| Manufacturer | Product family | - | <u>Capacitor</u> value | Linearity | Tuning | Package |
| ST Microelectronics | PTIC Parascan™ tunable Integrated capacitor | | 12 = 1.2 pF 27 = 2.7 pF 33 = 3.3 pF 39 = 3.9 pF 47 = 4.7 pF 56 = 5.6 pF 68 = 6.8 pF 82 = 8.2 pF | F: Standard (x24) G: Standard (x24) L: High (x48) | 1 = 4/1 tuning 2 = 5/1 tuning | M6 : QFN C5 : WLCSP |

Figure 15. Ordering information scheme

Table 9. Ordering information

| Part number | Marking | Base qty | Package | Delivery mode |
|---------------|---------|----------|-----------|---------------|
| STPTIC-82G2C5 | 82G | 15 000 | Flip-Chip | Tape and reel |

6 Revision history

| Date | Revision | Changes |
|-------------|----------|------------------|
| 09-Jul-2015 | 1 | Initial release. |



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